## **Dual Precision** Retriggerable/Resettable **Monostable Multivibrator**

The MC14538B is a dual, retriggerable, resettable monostable multivibrator. It may be triggered from either edge of an input pulse, and produces an accurate output pulse over a wide range of widths, the duration and accuracy of which are determined by the external timing components,  $C_X$  and  $R_X$ . Output Pulse Width  $T = R_X \cdot C_X$  (secs)

 $R_X = \Omega$  $C_X = Farads$ 

### **Features**

- Unlimited Rise and Fall Time Allowed on the A Trigger Input
- Pulse Width Range = 10 µs to 10 s
- Latched Trigger Inputs
- Separate Latched Reset Inputs
- 3.0 Vdc to 18 Vdc Operational Limits
- Triggerable from Positive (A Input) or Negative–Going Edge (B–Input)
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-pin Compatible with MC14528B and CD4528B (CD4098)
- Use the MC54/74HC4538A for Pulse Widths Less Than 10 us with Supplies Up to 6 V
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

### MAXIMUM RATINGS (Voltages Referenced to V<sub>SS</sub>)

| Symbol                             | Parameter   | Value                         | Unit |
|------------------------------------|---|-------------------------------|------|
| $V_{DD}$                           | DC Supply Voltage Range                           | -0.5 to +18.0                 | V    |
| V <sub>in</sub> , V <sub>out</sub> | Input or Output Voltage Range (DC or Transient)   | -0.5 to V <sub>DD</sub> + 0.5 | V    |
| I <sub>in</sub> , I <sub>out</sub> | Input or Output Current (DC or Transient) per Pin | ±10                           | mA   |
| P <sub>D</sub>                     | Power Dissipation, per Package (Note 1)           | 500                           | mW   |
| T <sub>A</sub>                     | Operating Temperature Range                       | -55 to +125                   | °C   |
| T <sub>stg</sub>                   | Storage Temperature Range                         | -65 to +150                   | °C   |
| TL                                 | Lead Temperature (8–Second Soldering)             | 260                           | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C From 65°C To 125°C This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{\text{in}}$  and  $V_{\text{out}}$  should be constrained to the range  $V_{SS} \le (V_{in} \text{ or } V_{out}) \le V_{DD}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V<sub>SS</sub> or V<sub>DD</sub>). Unused outputs must be left open.



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SOIC-16WB **DW SUFFIX CASE 751G** 

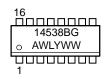


TSSOP-16 **DT SUFFIX** CASE 948F

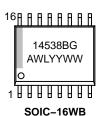


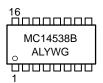
SOEIAJ-16 **F SUFFIX CASE 966** 

### MARKING DIAGRAMS



SOIC-16





538B ALYW= 188888888

16 <u>AAAAAA</u>

TSSOP-16

Α

SOEIAJ-16

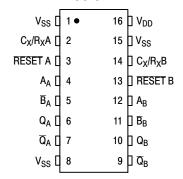
= Assembly Location WL, L = Wafer Lot YY, Y = Year WW. W = Work Week = Pb-Free Indicator

(Note: Microdot may be in either location)

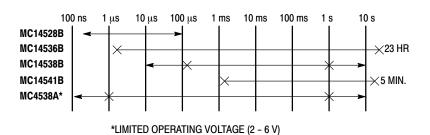
### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

### **PIN ASSIGNMENT**



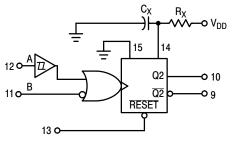
### **ONE-SHOT SELECTION GUIDE**



TOTAL OUTPUT PULSE WIDTH RANGE RECOMMENDED PULSE WIDTH RANGE X

# $\begin{array}{c|c} C_X & R_X \\ \hline & & \\$

**BLOCK DIAGRAM** 



 $R_X$  and  $C_X$  are external components.  $V_{DD}$  = PIN 16  $V_{SS}$  = PIN 8, PIN 1, PIN 15

### **ORDERING INFORMATION**

| Device          | Package                 | Shipping <sup>†</sup>    |
|-----------------|-------------------------|--------------------------|
| MC14538BDG      | SOIC-16<br>(Pb-Free)    | 48 Units / Rail          |
| NLV14538BDG*    | SOIC-16<br>(Pb-Free)    | 48 Units / Rail          |
| MC14538BDR2G    | SOIC-16<br>(Pb-Free)    | 2500 Units / Tape & Reel |
| NLV14538BDR2G*  | SOIC-16<br>(Pb-Free)    | 2500 Units / Tape & Reel |
| MC14538BDTR2G   | TSSOP-16<br>(Pb-Free)   | 2500 Units / Tape & Reel |
| NLV14538BDTR2G* | TSSOP-16<br>(Pb-Free)   | 2500 Units / Tape & Reel |
| MC14538BDWG     | SOIC-16 WB<br>(Pb-Free) | 47 Units / Rail          |
| NLV14538BDWG*   | SOIC-16 WB<br>(Pb-Free) | 47 Units / Rail          |
| MC14538BDWR2G   | SOIC-16 WB<br>(Pb-Free) | 1000 Units / Tape & Reel |
| NLV14538BDWR2G* | SOIC-16 WB<br>(Pb-Free) | 1000 Units / Tape & Reel |
| MC14538BFG      | SOEIAJ-16<br>(Pb-Free)  | 50 Units / Rail          |
| MC14538BFELG    | SOEIAJ-16<br>(Pb-Free)  | 2000 Units / Tape & Reel |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

### **ELECTRICAL CHARACTERISTICS** (Voltages Referenced to V<sub>SS</sub>)

|   |         |                 | v                      | - 5                           | 5°C  |  | 25°C   |  | 12   | 5°C                  |      |
|---|---------|-----------------|------------------------|-------------------------------|--|--|--|--|--|----------------------|------|
| Characteristic  |         | Symbol          | V <sub>DD</sub><br>Vdc | Min                           | Max  | Min  | Typ<br>(Note 2)  | Max  | Min  | Max                  | Unit |
| Output Voltage "0 V <sub>in</sub> = V <sub>DD</sub> or 0  | " Level | V <sub>OL</sub> | 5.0<br>10<br>15        | -<br>-<br>-                   | 0.05<br>0.05<br>0.05                                     | -<br>-<br>-  | 0<br>0<br>0  | 0.05<br>0.05<br>0.05   | -<br>-<br>-  | 0.05<br>0.05<br>0.05 | Vdc  |
| V <sub>in</sub> = 0 or V <sub>DD</sub> "1   | " Level | V <sub>OH</sub> | 5.0<br>10<br>15        | 4.95<br>9.95<br>14.95         | -<br>-<br>-  | 4.95<br>9.95<br>14.95  | 5.0<br>10<br>15  | -<br>-<br>-  | 4.95<br>9.95<br>14.95  | -<br>-<br>-          | Vdc  |
| Input Voltage "0<br>(V <sub>O</sub> = 4.5 or 0.5 Vdc)<br>(V <sub>O</sub> = 9.0 or 1.0 Vdc)<br>(V <sub>O</sub> = 13.5 or 1.5 Vdc)                      | " Level | V <sub>IL</sub> | 5.0<br>10<br>15        | -<br>-<br>-                   | 1.5<br>3.0<br>4.0  | _<br>_<br>_  | 2.25<br>4.50<br>6.75   | 1.5<br>3.0<br>4.0  | -<br>-<br>-  | 1.5<br>3.0<br>4.0    | Vdc  |
| $(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$<br>$(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$<br>$(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$                  | " Level | V <sub>IH</sub> | 5.0<br>10<br>15        | 3.5<br>7.0<br>11              | -<br>-<br>-  | 3.5<br>7.0<br>11   | 2.75<br>5.50<br>8.25   | -<br>-<br>-  | 3.5<br>7.0<br>11   | -<br>-<br>-          | Vdc  |
| Output Drive Current<br>$(V_{OH} = 2.5 \text{ Vdc})$<br>$(V_{OH} = 4.6 \text{ Vdc})$<br>$(V_{OH} = 9.5 \text{ Vdc})$<br>$(V_{OH} = 13.5 \text{ Vdc})$ | Source  | ІОН             | 5.0<br>5.0<br>10<br>15 | -3.0<br>-0.64<br>-1.6<br>-4.2 | -<br>-<br>-  | -2.4<br>-0.51<br>-1.3<br>-3.4  | -4.2<br>-0.88<br>-2.25<br>-8.8   | -<br>-<br>-  | -1.7<br>-0.36<br>-0.9<br>-2.4  |                      | mAdc |
| $(V_{OL} = 0.4 \text{ Vdc})$<br>$(V_{OL} = 0.5 \text{ Vdc})$<br>$(V_{OL} = 1.5 \text{ Vdc})$  | Sink    | I <sub>OL</sub> | 5.0<br>10<br>15        | 0.64<br>1.6<br>4.2            | -<br>-<br>-  | 0.51<br>1.3<br>3.4   | 0.88<br>2.25<br>8.8  | -<br>-<br>-  | 0.36<br>0.9<br>2.4   | -<br>-<br>-          | mAdc |
| Input Current, Pin 2 or 14  |         | l <sub>in</sub> | 15                     | -                             | ±0.05  | -  | ±0.00001   | ±0.05  | -  | ±0.5                 | μAdc |
| Input Current, Other Inputs   |         | l <sub>in</sub> | 15                     | _                             | ±0.1   | -  | ±0.00001   | ±0.1   | -  | ±1.0                 | μAdc |
| Input Capacitance, Pin 2 or 14  |         | C <sub>in</sub> | _                      | -                             | _  | -  | 25   | -  | -  | -                    | pF   |
| Input Capacitance, Other Inpu<br>(V <sub>in</sub> = 0)  | ts      | C <sub>in</sub> | -                      | -                             | -  | _  | 5.0  | 7.5  | -  | -                    | pF   |
| Quiescent Current<br>(Per Package)<br>Q = Low, Q = High   |         | I <sub>DD</sub> | 5.0<br>10<br>15        | -<br>-<br>-                   | 5.0<br>10<br>20  | -<br>-<br>-  | 0.005<br>0.010<br>0.015  | 5.0<br>10<br>20  | -<br>-<br>-  | 150<br>300<br>600    | μAdc |
| Quiescent Current, Active State (Both) (Per Package) Q = High, Q = Low  | te      | I <sub>DD</sub> | 5.0<br>10<br>15        | -<br>-<br>-                   | 2.0<br>2.0<br>2.0  | -<br>-<br>-  | 0.04<br>0.08<br>0.13   | 0.20<br>0.45<br>0.70   | -<br>-<br>-  | 2.0<br>2.0<br>2.0    | mAdc |
| Total Supply Current at an external load capacitance (C <sub>L</sub> ) and at external timing network (R <sub>X</sub> , C <sub>X</sub> ) (Note 3)     |         | I <sub>T</sub>  | 5.0<br>10              |                               | $I_T = (8.0 \text{ s})$<br>$I_T = (1.25 \text{ where:})$ | x 10 <sup>-2</sup> ) R<br>5 x 10 <sup>-1</sup> ) I<br>I <sub>T</sub> in μA (c<br>C <sub>X</sub> in μF, | $_{\chi}$ C <sub><math>\chi</math></sub> f + 4C <sub><math>\chi</math></sub> f + 9C <sub><math>\chi</math></sub> f + 9C <sub><math>\chi</math></sub> f + 12C one monosta C <sub><math>L</math></sub> in pF, R <sub><math>\chi</math></sub> | + 2 x 10 <sup>-5</sup><br>$\chi$ f + 3 x 10<br>ble switch<br>in k ohms | <sup>5</sup> C <sub>L</sub> f<br>0 <sup>–5</sup> C <sub>L</sub> f<br>ning only), |                      | μAdc |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

### **OPERATING CONDITIONS**

| External Timing Resistance  | $R_X$          | - | 5.0 | - | (Note 4) | kΩ |
|-----------------------------|----------------|---|-----|---|----------|----|
| External Timing Capacitance | C <sub>X</sub> | - | 0   | - | No Limit | μF |
|                             |                |   |     |   | (Note 5) |    |

<sup>4.</sup> The maximum usable resistance R<sub>X</sub> is a function of the leakage of the capacitor C<sub>X</sub>, leakage of the MC14538B, and leakage due to board layout and surface resistance. Susceptibility to externally induced noise signals may occur for  $R_X > 1 \ M\Omega$ .

<sup>5.</sup> If  $C_X > 15 \mu F$ , use discharge protection diode per Fig. 11.

### SWITCHING CHARACTERISTICS (Note 6) ( $C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$ )

|   |   | .,                     |                      | All Types             |                      |      |  |
|---|---|------------------------|----------------------|-----------------------|----------------------|------|--|
| Characteristic  | Symbol  | V <sub>DD</sub><br>Vdc | Min                  | Typ<br>(Note 7)       | Max                  | Unit |  |
| Output Rise Time $t_{TLH} = (1.35 \text{ ns/pF}) \text{ C}_{L} + 33 \text{ ns}$ $t_{TLH} = (0.60 \text{ ns/pF}) \text{ C}_{L} + 20 \text{ ns}$ $t_{TLH} = (0.40 \text{ ns/pF}) \text{ C}_{L} + 20 \text{ ns}$   | t <sub>TLH</sub>  | 5.0<br>10<br>15        | -<br>-<br>-          | 100<br>50<br>40       | 200<br>100<br>80     | ns   |  |
| Output Fall Time $t_{THL} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$ $t_{THL} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{THL} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$                                 | t <sub>THL</sub>  | 5.0<br>10<br>15        | -<br>-<br>-          | 100<br>50<br>40       | 200<br>100<br>80     | ns   |  |
| Propagation Delay Time A or B to Q or $\overline{Q}$ $t_{PLH}$ , $t_{PHL}$ = (0.90 ns/pF) $C_L$ + 255 ns $t_{PLH}$ , $t_{PHL}$ = (0.36 ns/pF) $C_L$ + 132 ns $t_{PLH}$ , $t_{PHL}$ = (0.26 ns/pF) $C_L$ + 87 ns | t <sub>PLH</sub> ,<br>t <sub>PHL</sub>                      | 5.0<br>10<br>15        |                      | 300<br>150<br>100     | 600<br>300<br>220    | ns   |  |
| Reset to Q or $\overline{Q}$<br>$t_{PLH}$ , $t_{PHL}$ = (0.90 ns/pF) $C_L$ + 205 ns<br>$t_{PLH}$ , $t_{PHL}$ = (0.36 ns/pF) $C_L$ + 107 ns<br>$t_{PLH}$ , $t_{PHL}$ = (0.26 ns/pF) $C_L$ + 82 ns                |   | 5.0<br>10<br>15        | -<br>-<br>-          | 250<br>125<br>95      | 500<br>250<br>190    | ns   |  |
| Input Rise and Fall Times Reset   | t <sub>r</sub> , t <sub>f</sub>                             | 5<br>10<br>15          | -<br>-<br>-          | -<br>-<br>-           | 15<br>5<br>4         | μs   |  |
| B Input   |   | 5<br>10<br>15          | -<br>-<br>-          | 300<br>1.2<br>0.4     | 1.0<br>0.1<br>0.05   | ms   |  |
| A Input   |   | 5<br>10<br>15          |                      | No Limit              |                      | -    |  |
| Input Pulse Width<br>A, B, or Reset   | t <sub>WH</sub> ,<br>t <sub>WL</sub>                        | 5.0<br>10<br>15        | 170<br>90<br>80      | 85<br>45<br>40        | -<br>-<br>-          | ns   |  |
| Retrigger Time  | t <sub>rr</sub>   | 5.0<br>10<br>15        | 0<br>0<br>0          | _<br>_<br>_           | -<br>-<br>-          | ns   |  |
| Output Pulse Width — Q or $\overline{Q}$<br>Refer to Figures 8 and 9<br>$C_X$ = 0.002 $\mu$ F, $R_X$ = 100 $k\Omega$  | Т   | 5.0<br>10<br>15        | 198<br>200<br>202    | 210<br>212<br>214     | 230<br>232<br>234    | μs   |  |
| $C_X = 0.1 \mu F$ , $R_X = 100 \text{ k}\Omega$   |   | 5.0<br>10<br>15        | 9.3<br>9.4<br>9.5    | 9.86<br>10<br>10.14   | 10.5<br>10.6<br>10.7 | ms   |  |
| $C_X$ = 10 $\mu$ F, $R_X$ = 100 $k\Omega$   |   | 5.0<br>10<br>15        | 0.91<br>0.92<br>0.93 | 0.965<br>0.98<br>0.99 | 1.03<br>1.04<br>1.06 | S    |  |
| Pulse Width Match between circuits in the same package. $C_X = 0.1 \ \mu\text{F}, \ R_X = 100 \ k\Omega$  | 100<br>[(T <sub>1</sub> - T <sub>2</sub> )/T <sub>1</sub> ] | 5.0<br>10<br>15        | -<br>-<br>-          | ±1.0<br>±1.0<br>±1.0  | ±5.0<br>±5.0<br>±5.0 | %    |  |

<sup>6.</sup> The formulas given are for the typical characteristics only at 25°C.
7. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

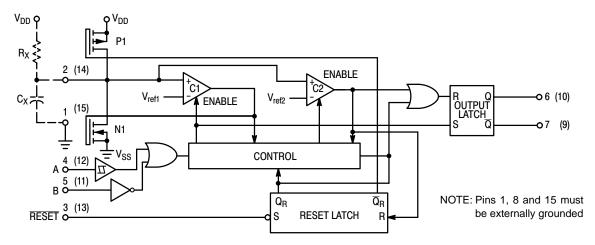


Figure 1. Logic Diagram (1/2 of Devlce Shown)

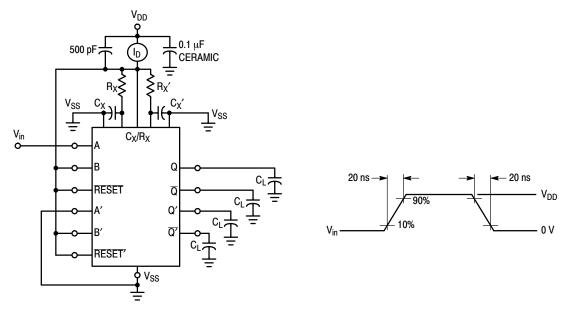


Figure 2. Power Dissipation Test Circuit and Waveforms

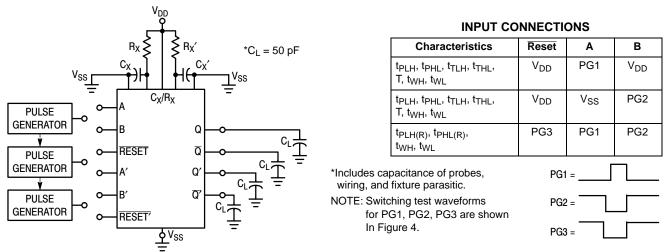


Figure 3. Switching Test Circuit

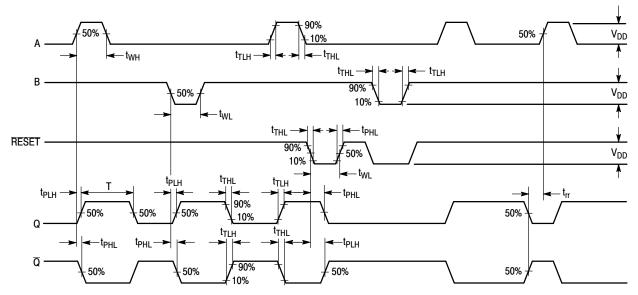


Figure 4. Switching Test Waveforms

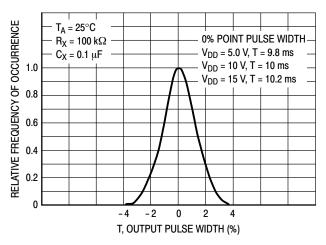


Figure 5. Typical Normalized Distribution of Units for Output Pulse Width

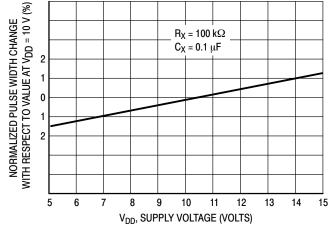


Figure 6. Typical Pulse Width Variation as a Function of Supply Voltage V<sub>DD</sub>

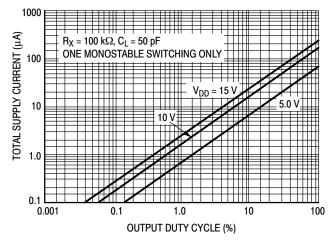


Figure 7. Typical Total Supply Current versus Output Duty Cycle

### **FUNCTION TABLE**

|        | Inputs              | Out          | puts                           |              |  |
|--------|---------------------|--------------|--------------------------------|--------------|--|
| Reset  | Α                   | В            | Q                              | Q            |  |
| H<br>H | \ ∟                 | τ            | 77                             | 디디           |  |
| H<br>H |                     |              | Not Triggered<br>Not Triggered |              |  |
| H<br>H | L, H, <b>∼</b><br>L | H<br>L, H, ✓ | Not Triggered<br>Not Triggered |              |  |
| L      | X<br>X              | X<br>X       | L<br>Not Tr                    | H<br>iggered |  |

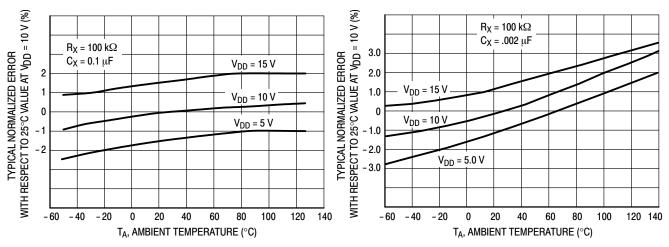


Figure 8. Typical Error of Pulse Width Equation versus Temperature

Figure 9. Typical Error of Pulse Width Equation versus Temperature

### THEORY OF OPERATION

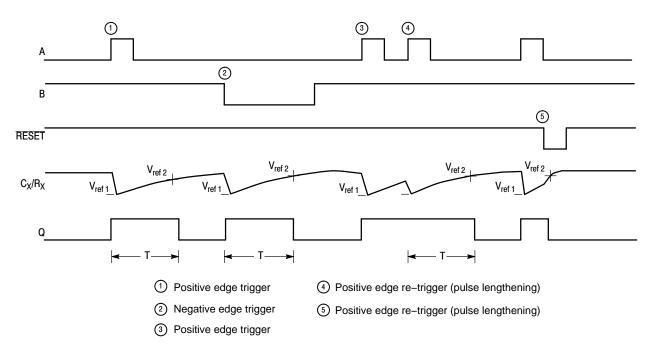


Figure 10. Timing Operation

### TRIGGER OPERATION

The block diagram of the MC14538B is shown in Figure 1, with circuit operation following.

As shown in Figure 1 and 10, before an input trigger occurs, the monostable is in the quiescent state with the Q output low, and the timing capacitor C<sub>X</sub> completely charged to  $V_{DD}$ . When the trigger input A goes from  $V_{SS}$  to  $V_{DD}$ (while inputs B and  $\overline{\text{Reset}}$  are held to  $V_{DD}$ ) a valid trigger is recognized, which turns on comparator C1 and N-channel transistor N1 ①. At the same time the output latch is set. With transistor N1 on, the capacitor C<sub>X</sub> rapidly discharges toward V<sub>SS</sub> until V<sub>ref1</sub> is reached. At this point the output of comparator C1 changes state and transistor N1 turns off. Comparator C1 then turns off while at the same time comparator C2 turns on. With transistor N1 off, the capacitor  $C_X$  begins to charge through the timing resistor,  $R_X$ , toward  $V_{DD}$ . When the voltage across  $C_X$  equals  $V_{ref 2}$ , comparator C2 changes state, causing the output latch to reset (Q goes low) while at the same time disabling comparator C2 ②. This ends at the timing cycle with the monostable in the quiescent state, waiting for the next trigger.

In the quiescent state,  $C_X$  is fully charged to  $V_{DD}$  causing the current through resistor  $R_X$  to be zero. Both comparators are "off" with total device current due only to reverse junction leakages. An added feature of the MC14538B is that the output latch is set via the input trigger without regard to the capacitor voltage. Thus, propagation delay from trigger to Q is independent of the value of  $C_X$ ,  $R_X$ , or the duty cycle of the input waveform.

### **RETRIGGER OPERATION**

The MC14538B is retriggered if a valid trigger occurs  $\ 3$  followed by another valid trigger  $\ 4$  before the Q output has returned to the quiescent (zero) state. Any retrigger, after the timing node voltage at pin 2 or 14 has begun to rise from  $V_{ref\ 1}$ , but has not yet reached  $V_{ref\ 2}$ , will cause an increase in output pulse width T. When a valid retrigger is initiated  $\ 4$ , the voltage at  $C_X/R_X$  will again drop to  $V_{ref\ 1}$  before progressing along the RC charging curve toward  $V_{DD}$ . The Q output will remain high until time T, after the last valid retrigger.

### **RESET OPERATION**

The MC14538B may be reset during the generation of the output pulse. In the reset mode of operation, an input pulse

on  $\overline{Reset}$  sets the reset latch and causes the capacitor to be fast charged to  $V_{DD}$  by turning on transistor P1 s. When the voltage on the capacitor reaches  $V_{ref\ 2}$ , the reset latch will clear, and will then be ready to accept another pulse. It the  $\overline{Reset}$  input is held low, any trigger inputs that occur will be inhibited and the Q and  $\overline{Q}$  outputs of the output latch will not change. Since the Q output is reset when an input low level is detected on the  $\overline{Reset}$  input, the output pulse T can be made significantly shorter than the minimum pulse width specification.

### **POWER-DOWN CONSIDERATIONS**

Large capacitance values can cause problems due to the large amount of energy stored. When a system containing the MC14538B is powered down, the capacitor voltage may discharge from  $V_{DD}$  through the standard protection diodes at pin 2 or 14. Current through the protection diodes should be limited to 10 mA and therefore the discharge time of the  $V_{DD}$  supply must not be faster than  $(V_{DD})$ . (C)/(10 mA). For example, if  $V_{DD}$  = 10 V and  $C_X$  = 10  $\mu F$ , the  $V_{DD}$  supply should discharge no faster than (10 V) x (10  $\mu F$ )/(10 mA) = 10 ms. This is normally not a problem since power supplies are heavily filtered and cannot discharge at this rate.

When a more rapid decrease of  $V_{DD}$  to zero volts occurs, the MC14538B can sustain damage. To avoid this possibility use an external clamping diode,  $D_X$ , connected as shown in Fig. 11.

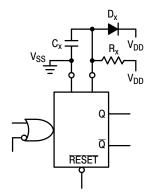
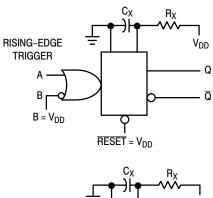


Figure 11. Use of a Diode to Limit Power Down Current Surge

### **TYPICAL APPLICATIONS**



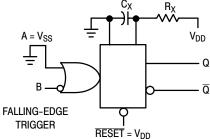


Figure 12. Retriggerable Monostables Circuitry

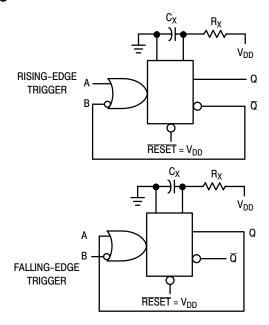
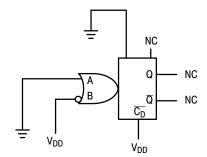


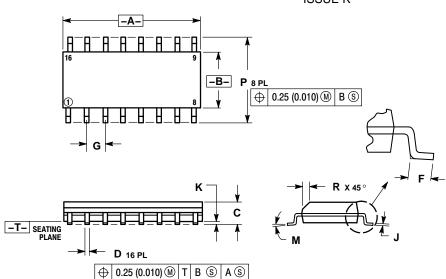
Figure 13. Non-Retriggerable Monostables Circuitry



**Figure 14. Connection of Unused Sections** 

### **PACKAGE DIMENSIONS**

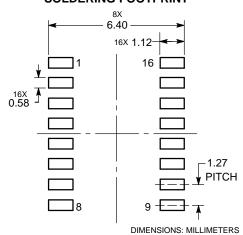
### SOIC-16 **D SUFFIX** CASE 751B-05 **ISSUE K**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

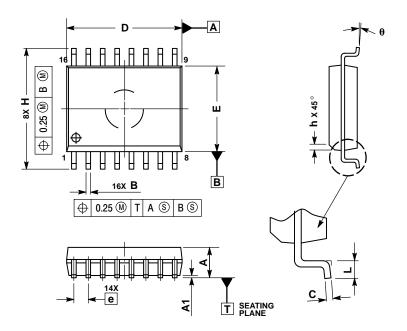
|     | MILLIMETERS |       | INC   | HES   |
|-----|-------------|-------|-------|-------|
| DIM | MIN         | MAX   | MIN   | MAX   |
| Α   | 9.80        | 10.00 | 0.386 | 0.393 |
| В   | 3.80        | 4.00  | 0.150 | 0.157 |
| C   | 1.35        | 1.75  | 0.054 | 0.068 |
| D   | 0.35        | 0.49  | 0.014 | 0.019 |
| F   | 0.40        | 1.25  | 0.016 | 0.049 |
| G   | 1.27        | BSC   | 0.050 | ) BSC |
| 7   | 0.19        | 0.25  | 0.008 | 0.009 |
| K   | 0.10        | 0.25  | 0.004 | 0.009 |
| M   | 0°          | 7°    | 0°    | 7°    |
| P   | 5.80        | 6.20  | 0.229 | 0.244 |
| R   | 0.25        | 0.50  | 0.010 | 0.019 |

### **SOLDERING FOOTPRINT**



### **PACKAGE DIMENSIONS**

### SOIC-16 WB **DW SUFFIX** CASE 751G-03 ISSUE D



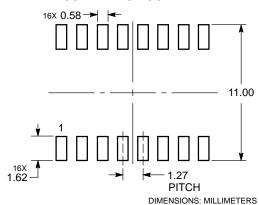
### NOTES:

- NOTES:

  1. DIMENSIONS ARE IN MILLIMETERS.
  2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
  3. DIMENSIONS D AND E DO NOT INLCUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
  5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

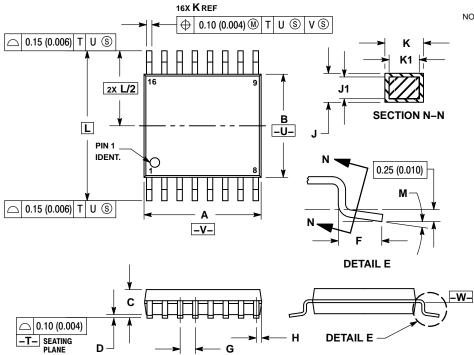
|     | MILLIMETERS |       |  |  |
|-----|-------------|-------|--|--|
| DIM | MIN         | MAX   |  |  |
| Α   | 2.35        | 2.65  |  |  |
| A1  | 0.10        | 0.25  |  |  |
| В   | 0.35        | 0.49  |  |  |
| С   | 0.23        | 0.32  |  |  |
| D   | 10.15       | 10.45 |  |  |
| Е   | 7.40        | 7.60  |  |  |
| е   | 1.27        | BSC   |  |  |
| Н   | 10.05       | 10.55 |  |  |
| h   | 0.25        | 0.75  |  |  |
| L   | 0.50        | 0.90  |  |  |
| q   | 0 °         | 7 °   |  |  |

### **SOLDERING FOOTPRINT**



### **PACKAGE DIMENSIONS**

### TSSOP-16 **DT SUFFIX** CASE 948F **ISSUE B**



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

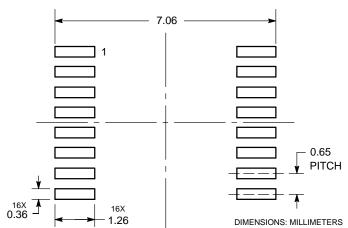
  5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. CONDITION.

  6. TERMINAL NUMBERS ARE SHOWN FOR

  - 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

|     | MILLIMETERS |      | TERS INCHES |       |
|-----|-------------|------|-------------|-------|
| DIM | MIN         | MAX  | MIN         | MAX   |
| Α   | 4.90        | 5.10 | 0.193       | 0.200 |
| В   | 4.30        | 4.50 | 0.169       | 0.177 |
| С   |             | 1.20 |             | 0.047 |
| D   | 0.05        | 0.15 | 0.002       | 0.006 |
| F   | 0.50        | 0.75 | 0.020       | 0.030 |
| G   | 0.65        | BSC  | 0.026 BSC   |       |
| Н   | 0.18        | 0.28 | 0.007       | 0.011 |
| J   | 0.09        | 0.20 | 0.004       | 0.008 |
| J1  | 0.09        | 0.16 | 0.004       | 0.006 |
| K   | 0.19        | 0.30 | 0.007       | 0.012 |
| K1  | 0.19        | 0.25 | 0.007       | 0.010 |
| L   | 6.40        |      | 0.252       | BSC   |
| М   | 0°          | 8°   | 0°          | 8 °   |

### **SOLDERING FOOTPRINT**



### PACKAGE DIMENSIONS

# SOEIAJ-16 F SUFFIX CASE 966 ISSUE A DETAIL P VIEW P 0.13 (0.005) (0) 0.10 (0.004)

### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  - . CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- (0.006) PER SIDE.

  4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

|                | MILLIN | IETERS | INC   | HES   |
|----------------|--------|--------|-------|-------|
| DIM            | MIN    | MAX    | MIN   | MAX   |
| Α              |        | 2.05   |       | 0.081 |
| A <sub>1</sub> | 0.05   | 0.20   | 0.002 | 0.008 |
| b              | 0.35   | 0.50   | 0.014 | 0.020 |
| С              | 0.10   | 0.20   | 0.007 | 0.011 |
| D              | 9.90   | 10.50  | 0.390 | 0.413 |
| Е              | 5.10   | 5.45   | 0.201 | 0.215 |
| е              | 1.27   | BSC    | 0.050 | BSC   |
| HE             | 7.40   | 8.20   | 0.291 | 0.323 |
| L              | 0.50   | 0.85   | 0.020 | 0.033 |
| LE             | 1.10   | 1.50   | 0.043 | 0.059 |
| M              | 0 °    | 10°    | 0°    | 10°   |
| Q <sub>1</sub> | 0.70   | 0.90   | 0.028 | 0.035 |
| Z              |        | 0.78   |       | 0.031 |

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